Notice of Allowability	Application No.	Applicant(s)	
	10/743,814	MATSUURA ET AL.	
	Examiner	Art Unit	
	Tu-Tu Ho	2818	
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.			
1. X This communication is responsive to Paper filed 09/30/2004.			
2. 🔀 The allowed claim(s) is/are <u>1-14</u> .			
3. 🔀 The drawings filed on <u>24 December 2003</u> are accepted by the Examiner.			
4.			
	8. ⊠ Examiner's Stateme 9. □ Other avid Neims	(PTO-413), e nent/Comment	·
Supervisory Patent Examiner Technology Center 2800			

DETAILED ACTION

Election/Restrictions

1. Claims 15-20 withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim.

Election was made without traverse in the reply filed on 09/30/2004.

Examiner's Amendment

- 2. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.
- 3. This application is in condition for allowance except for the presence of claims 15-20 non-elected without traverse. Accordingly, claims 15-20 have been cancelled.

Allowable Subject Matter

4. Claims 1-14 are allowable over the prior art of record.

The following is an examiner's statement of reasons for allowance: The prior art of record fails to teach or render obvious a ferroelectric capacitor having all exclusive limitations as recited in claims 1 and 14, comprising a pair of electrodes sandwiching a multi-layer ferroelectric layer comprising a first ferroelectric layer and a second ferroelectric layer, the first ferroelectric layer

having a surface roughness (RMS) of 10 nm or more and the second ferroelectric layer having a surface roughness (RMS) of 5 nm or less, the RMS surface roughness being determined by an atomic force microscope.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

- 5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Copies of the references are not being furnished with this Office Action per MPEP § 707.05(a).
- a) U.S. Patent 6,121,647 to Yano et al. discloses a ferroelectric film on a surface of a substrate, the ferroelectric film comprising lead and a rare earth element of a particular atomic ratio and having a particular orientation.
- b) U.S. Patent 6,664,116 to Li et al. discloses a method of forming a ferroelectric thin film on a high-k layer includes preparing a silicon substrate, forming a high-k layer on the substrate, depositing a seed layer of ferroelectric material at a relatively high temperature on the high-k layer, depositing a top layer of ferroelectric material on the seed layer at a relatively low temperature, and annealing the substrate, the high-k layer and the ferroelectric layers to form a ferroelectric thin film.

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6. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Tu-Tu Ho whose telephone number is (571) 272-1778. The

examiner can normally be reached on 6:30 am - 5:00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, DAVID NELMS can be reached on (571) 272-1787. The fax phone number for the

organization where this application or proceeding is assigned is (703) 872-9306.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

TH

Tu-Tu Ho

October 21, 2004

David Nelms

Supervisory Patent Examiner Technology Center 2800